

Low voltage high performance NPN power transistor

Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed

Applications

- Emergency lighting
- LED drive
- Motherboard and hard disk drive
- Mobile equipment
- DC-DC converter, voltage regulation



osolete P

The device is a NPN transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

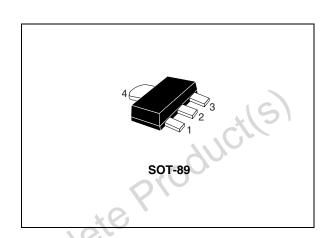


Figure 1. Internal schematic diagram

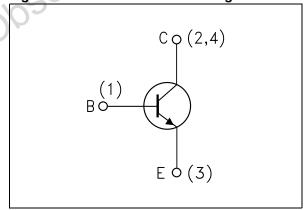


Table 1. Device summary

Order codes	Marking	Package	Packaging
2STF1525	1525	SOT-89	Tape and reel

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Electrical ratings 2STF1525

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CEX}	Collector-emitter voltage (V _{BE} = - 1.5 V)	95	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	25	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I _C	Collector current	5	Α
I _{CM}	Collector peak current (t _P < 5 ms)	10	Α
I _B	Base current	1	A
P _{TOT}	Total dissipation at T _{amb} = 25 °C	1.4	W
T _{STG}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient max	89	°C/W

^{1.} Device mounted on PCB area of 1 cm²

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 50 V			0.1	μΑ
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 4 V			0.1	μΑ
V _{(BR)CEX}	Collector-emitter breakdown voltage (V _{BE} = -1.5 V)	I _C = 1 mA	95	401	316	٧
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = 10 mA	25	O. J		٧
V _{(BR)EBO}	Emitter-base breakdown voltage ($I_C = 0$)	Ι _Ε = 100 μΑ	5			٧
h _{FE} ⁽¹⁾	DC current gain	$\begin{split} I_{C} &= 0.5 \text{ A} & V_{CE} &= 2 \text{ V} \\ I_{C} &= 3 \text{ A} & V_{CE} &= 2 \text{ V} \\ I_{C} &= 5 \text{ A} & V_{CE} &= 5 \text{ V} \end{split}$	150 100	150	500	
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 3 \text{ A}$ $I_B = 300 \text{ mA}$ $I_C = 3.5 \text{ A}$ $I_B = 40 \text{ mA}$		220	500	mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 3 A I _B = 300 mA			1.2	V
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = 10 V, f = 1 MHz		20		pF
fτ	Transition frequency	V _{CE} = 10 V I _C = 50 mA		120		MHz
t _{on} t _{off}	Resistive load Turn-on time Turn-off time	$I_C = 1.5 \text{ A}$ $V_{CC} = 10 \text{ V}$ $I_{B1} = -I_{B2} = 150 \text{ mA}$		60 450		ns ns

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %

3 Package mechanical data

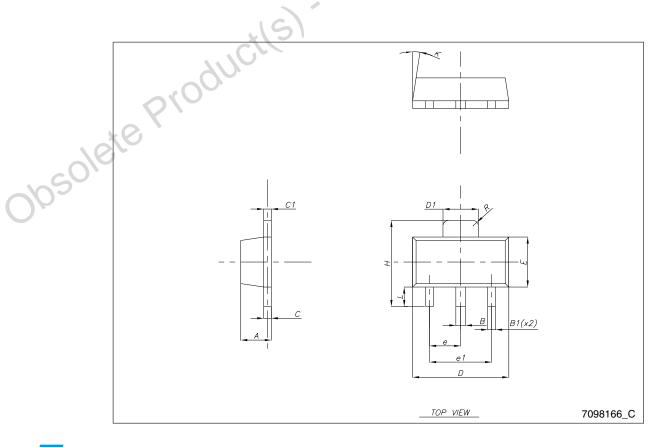
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SOT-89 mechanical data

Dim.	mm			
υim.	Min.	Тур.	Max.	
A	1.40		1.60	
В	0.44		0.56	
B1	0.36		0.48	
С	0.35		0.44	
C1	0.35		0.44	
D	4.40		4.60	
D1	1.62		1.83	
E	2.29		2.60	
е	1.42		1.57	
e1	2.92	210	3.07	
Н	3.94		4.25	
К	1°	40	8°	
L	0.89	18,	1.20	
R	C	0.25		



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Revision history 2STF1525

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
04-Jun-2009	1	Initial release.
12-Nov-2009	2	Document status promoted from preliminary data to datasheet.



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